

# Attachment A

L Number	Hits	Search Text	DB	Time stamp
1	56605	sram or (static near2 (ram or memory))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:02
2	69256	bitline or (bit near line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:02
3	60624	wordline or (word near line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:03
4	40178	sense near2 amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:03
5	231340	decoder	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:05
6	139557	operat\$3 near2 voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:05
7	34015	(threshold near2 voltage) near9 transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:07
8	224159	(reduc\$4 or minimiz\$4) near2 power	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:08
9	12559	(sram or (static near2 (ram or memory))) and (bitline or (bit near line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:08
10	9193	((sram or (static near2 (ram or memory))) and (bitline or (bit near line))) and (wordline or (word near line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:08
11	5024	((((sram or (static near2 (ram or memory))) and (bitline or (bit near line))) and (wordline or (word near line))) and (sense near2 amplifier))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:08
12	3805	((((sram or (static near2 (ram or memory))) and (bitline or (bit near line))) and (wordline or (word near line))) and (sense near2 amplifier)) and decoder	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:08
13	1301	(((((sram or (static near2 (ram or memory))) and (bitline or (bit near line))) and (wordline or (word near line))) and (sense near2 amplifier)) and decoder) and (operat\$3 near2 voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:08

14	640	(((((sram or (static near2 (ram or memory))) and (bitline or (bit near line))) and (wordline or (word near line))) and (sense near2 amplifier)) and decoder) and (operat\$3 near2 voltage)) and ((threshold near2 voltage) near9 transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:09
15	1239	(gate near9 thicker) near9 transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:10
16	48	(((((sram or (static near2 (ram or memory))) and (bitline or (bit near line))) and (wordline or (word near line))) and (sense near2 amplifier)) and decoder) and (operat\$3 near2 voltage)) and ((threshold near2 voltage) near9 transistor)) and ((gate near9 thicker) near9 transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:10
17	48	(((((sram or (static near2 (ram or memory))) and (bitline or (bit near line))) and (wordline or (word near line))) and (sense near2 amplifier)) and decoder) and (operat\$3 near2 voltage)) and ((threshold near2 voltage) near9 transistor)) and ((gate near9 thicker) near9 transistor)) and (higher near9 voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/04 14:10

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